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Microstructure and magneto-optical properties of Pr–Ni substituted Ba hexaferrite films prepared by sputtering

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Hexaferrite thin films of Ba$_{1-x}$R$_{x}$Fe$_{12-x}$Ni$_{x}$O$_{19}$ (R=Pr, La) were grown on nonmagnetic garnet substrates by rf sputtering. When deposited at a substrate temperature of 550 °C at rf power density (PD$_{rf}$) larger than 19 W/cm$^2$, the films were completely crystallized, with the c axis preferentially oriented normal to the film plane. Transmission electron microscopy revealed that the films deposited at low PD$_{rf}$ were amorphous but locally contained microcrystallites several nm in size. On the other hand, the films deposited at PD$_{rf}$ larger than 20 W/cm$^2$ were polycrystalline with a crystallite size as large as 300 nm. Faraday rotation measurements showed that the Ni substitution induced a large negative rotation in the photon energy range of 2.1–2.6 eV. This Ni contribution was predominantly attributed to the crystal-field transition of octahedrally coordinated Ni$^{2+}$ ions lying in the 2 eV range. No contribution by Pr$^{3+}$ ions to the Faraday rotation was observed within the photon energy range measured. © 1997 American Institute of Physics.

I. INTRODUCTION

Substitution of specific ions such as Bi$^{3+}$, Co$^{2+}$, and light rare earth ions into garnet and spinel ferrites significantly enhances magneto-optical (MO) activity. This enhancement is strongly affected not only by the valence state of the enhancement ion but also by the crystallographic environment surrounding the enhancement ion. In fact, it is well known that octahedrally coordinated Co$^{2+}$ ions in spinel ferrites exhibits little MO enhancement compared with tetrahedrally coordinated Co$^{2+}$. Hexagonal ferrites with the magnetoplumbite (M-type) crystal structure contain both alkaline earth ions and transition metal ions, part of which permits replacements by the above enhancement ions with various ionic radii. Therefore, it is useful to compare the MO activity of the enhancement ions in the hexaferrites with that in rare earth iron garnet in order to clarify the MO behavior of the enhancement ions in different crystallographic sites. Abe and Gomi reported that tetrahedrally coordinated Co$^{2+}$ ions in hexagonal ferrites gives rise to a large MO effect due to the $^{4}A_{2}$→$^{4}T_{1}(P)$ and $^{4}A_{2}$→$^{4}T_{1}(F)$ crystal-field transitions around 2.0 and 0.8 eV, respectively. However, with the exception of the above and a recent theoretical study, few studies have been performed on the MO effect of the hexaferrites. This is primarily because the hexaferrite has a complicated crystal structure that makes detailed analysis of the spectrum particularly difficult. In addition, MO measurement requires a specific film with the c axis preferentially oriented normal to the film plane in order to avoid birefringence.

II. EXPERIMENT

The films of Ba$_{1-x}$R$_{x}$Fe$_{12-x}$Ni$_{x}$O$_{19}$ (R=Pr, La, x=0, 0.3, 0.6) were deposited on Gd$_3$Ga$_5$O$_{12}$ (GGG) single crystal substrates at temperatures ($T_s$) of 400–600 °C using conventional rf diode sputtering. Ceramic disks (70 mm in diameter) were used as targets, the nominal compositions of which are summarized in Table I, along with other sputtering parameters. The trivalent R ions substituted for the Ba$^{2+}$ ions were charge compensated by the same number of divalent Ni ions replaced for the Fe$^{3+}$ ions. Since the resputtering of the Ba element from the film surface by the bombardment of high energy ions during deposition was much greater than that of the other element, it was overdosed in the targets. The chemical composition of the films was determined by the inductively coupled plasma (ICP) method and by x-ray microanalysis. The crystal structure, surface morphology, and microstructure of the prepared films were evaluated by x-ray diffractometry (XRD), scanning electron microscopy (SEM), and transmission electron microscopy (TEM),

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TABLE I. Target compositions and sputtering conditions.

<table>
<thead>
<tr>
<th>Target</th>
<th>Ba1.33(1−x)PrxFe12−xNi0.5O19+y (R=Pr, La, x=0, 0.3, 0.6)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sputter gas</td>
<td>Ar:O2=9:1</td>
</tr>
<tr>
<td>Gas pressure</td>
<td>50 mTorr</td>
</tr>
<tr>
<td>Incident rf power density</td>
<td>6–24 W/cm²</td>
</tr>
<tr>
<td>Deposition rate</td>
<td>7–20 nm/min</td>
</tr>
<tr>
<td>Substrate temperature</td>
<td>400–600 °C</td>
</tr>
</tbody>
</table>

TABLE II. Typical compositions per formula unit of films sputtered at 20 W/cm², on the other hand, showed much a greater surging in the diffraction of the selected area. The film deposited embedded in the amorphous matrix and caused the broad

respectively. The Faraday rotation of the films was measured by the polarization modulation method in the photon energy range of 1.5–3 eV.

III. RESULTS AND DISCUSSION

A. Structural and magnetic properties

Typical compositions of the films are compiled in Table II, where the atomic ratio was calculated on the assumption that the amount of Fe per formula unit in the film was equal to that of the target. The film compositions are close to those of the targets, although Ni is slightly richer. It was confirmed that the film composition is nearly independent of the power density (PD rf) of the rf discharge which is a significant parameter that dominates crystallization of the film during deposition.

When $T_s<550$ °C and PD rf$<19$ W/cm², the films were x-ray amorphous. On the other hand, as the typical XRD spectra of Fig. 1 show, all films deposited at PD rf and/or $T_s$ higher than the above values were fully crystallized in the single phase of M-type hexaferrite with the c axis preferentially oriented perpendicular to the film plane. The increase of the substituted amount x decreased the film quality, as shown in Fig. 2. This is because the increased x induced locally large lattice distortions caused by the difference between the ionic radius of the Ba$^{2+}$ ion and the substituted $R^{3+}$ ion; these distortions resulted in poor crystallinity.

Figure 3 shows typical SEM images of the surface and cross section of Ba$_{1−x}$Pr$_x$Fe$_{12−x}$Ni$_x$O$_{19}$ (x = 0.38) films deposited at PD rf = 9 W/cm² [Figs. 3(a) and 3(a’)] and 20 W/cm² [Figs. 3(b) and 3(b’)]. The bright field TEM images and selected area diffraction patterns of these films are presented in Fig. 4. The surface of the film deposited at 9 W/cm² shows a fine structure, although the film is x-ray amorphous. The TEM observation of this film [Figs. 4(a) and 4(a’)] indicated that microcrystallites several nm in size were embedded in the amorphous matrix and caused the broad ring in the diffraction of the selected area. The film deposited at 20 W/cm², on the other hand, showed much a greater surface structure. The surface roughness was somewhat smaller than that of the Ba ferrite film shown in Fig. 3(c) for comparison. The single-crystal-like diffraction spots observed at the selected area of about 400 nm in diameter suggested that crystal grains as large as 200–300 nm were present in the film.

The microstructure of the films has significant influence on the magnetic properties. Figure 5 shows the saturation magnetization ($M_s$), coercive force ($H_c$), and ratio ($R_s$) of remanent magnetization to $M_s$ in Ba$_{1−x}$Pr$_x$Fe$_{12−x}$Ni$_x$O$_{19}$ (x = 0.38) films at room temperature, plotted as a function of PD rf. With increasing PD rf, $M_s$ is elevated, reaching 320emu/cc at PD rf = 15 W/cm², while $H_c$ and $R_s$ are reduced linearly. We obtained the same $M_s$ of 380 emu/cc as the bulk value for the nonsubstituted Ba hexaferrite films deposited at

\[ T_s=550°C \]

FIG. 1. Typical x-ray diffraction spectra of BaM films sputtered at various rf power densities and $T_s=550$ °C.

FIG. 2. X-ray diffraction spectra of the (00014) plane for films with x = 0, 0.37, and 0.78.
The dependence of these properties on $PD_{rf}$ is associated with the size, quality, and density of the crystallites produced in the films: In low $PD_{rf}$, the fine crystallites with a magnetic moment are precipitated in the non-magnetic amorphous matrix as shown in Fig. 4, which results in the high $H_c$ and low $M_s$ of the films.

**B. Magneto-optical properties**

Figures 6(a) and 6(b), respectively, compare Faraday rotation spectra of the Pr–Ni substituted BaM films and the La–Ni substituted BaM films at room temperature with those of the BaM film. The spectrum for the BaM film shows some
structure around 1.7, 2.0, 2.3, and above 2.5 eV. The structures below 2.3 eV are assigned to the crystal-field transitions of Fe$^{3+}$ octahedrally and tetrahedrally coordinated with O$^{2-}$ ions. This is because the observed structures have narrow spectral widths and because the optical absorption measurement showed weak peaks superimposed on a strong absorption edge at the energy positions. These observed energy positions are consistent with the previously reported positions of crystal-field transitions of the iron garnet crystal. The structure above 2.5 eV is probably associated with other transitions with stronger oscillator strength located at higher energy, such as a charge transfer transition. However, details of this association are not clear at present.

As the Ni concentration increases, the Faraday rotation of the Pr–Ni substituted BaM film is reduced in the region below 2.1 eV, and especially at around 1.7 and 2.0 eV. But its negative value is enhanced in the region above 2.1 eV. The enhancement factor is as large as $1.1 \times 10^4$ deg/cm per $x=0.78$ at 2.5 eV, comparable to that of the Co$^{2+}$ substitution reported previously ($1.3 \times 10^4$ deg/cm per Co$^{2+}$ ion at 2.0 eV). Similar spectral changes were obtained for the films substituted by the nonmagnetic La ion instead of the Pr ion, as shown in Fig. 6(b). This implies that the Pr$^{3+}$ ion that induces a large negative rotation in the iron garnet makes no

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**FIG. 4.** Bright field TEM images ([a] and [b]) and selected area diffraction patterns ([a'] and [b']) of Ba$_{1-x}$Pr$_x$Fe$_{12-x}$Ni$_x$O$_{19}$ ($x=0.38$) films deposited at different rf power densities. The circles in the bright field images show the selected areas for electron diffraction.

**FIG. 5.** Saturation magnetization $M_s$, coercive force $H_c$, and ratio $R_s$ of remnant magnetization to $M_s$ for Ba$_{1-x}$Pr$_x$Fe$_{12-x}$Ni$_x$O$_{19}$ ($x=0.38$) films at room temperature, plotted as a function of rf power density PD$_{rf}$.
comparable contribution in the hexaferrite, at least within the photon energy range measured. Therefore, the substituted Ni$^{2+}$ ions are primarily responsible for the observed spectral changes.

Figure 7 shows the apparent Ni$^{2+}$ contribution obtained by subtracting the Faraday rotation spectrum of the nonsubstituted film from that of the La–Ni substituted film. It should be noted here that the subtracted values include the reduction of Faraday rotation caused by the deterioration of crystal quality. The poor crystallinity of the film induced by increasing the Ni$^{2+}$ substitution significantly reduced the Faraday rotation, especially around the crystal-field transitions. Thus, the subtracted spectra overestimate the Ni$^{2+}$ contribution around 1.7 and 2.0 eV, and underestimate it around 2.3 eV. The dotted curve in Fig. 7 shows the intrinsic Ni$^{2+}$ contribution schematically. The Ni$^{2+}$ contribution has an asymmetric spectral shape showing large negative Faraday rotation in the range of 2.1–2.6 eV and small positive rotation below 2.1 eV.

To specify the lattice sites that the Ni ions preferentially occupy in the hexaferrite, we measured x-ray photoelectron spectra of Ni 2$p_{3/2}$ in the La–Ni substituted BaM film and in the Pr–Ni substituted BaM film. Figure 8 shows the results. The Ni 2$p$ spectra of both films have the same binding energy (854 eV) and satellite-separation energy (7 eV) as that measured in a referent NiZn-ferrite film. This indicates that the Ni$^{2+}$ ions preferentially occupy octahedrally coordinated sites in the hexaferrite as well as in the spinel ferrite. Papallo et al. have reported that a broad optical absorption due to a group of crystal-field transitions $^4A_2–^2F_1$, $^4E$ of octahedrally coordinated Ni$^{2+}$ is observed for Ni-doped MgAl$_2$O$_4$ in the range of 1.9–2.5 eV. We also confirmed from the diffuse reflection measurements for the ceramics of a La–Ni substituted Ba hexagallate (Ba$_{0.7}$La$_{0.3}$Ga$_{11.7}$Ni$_{0.3}$O$_{19}$) that a broad absorption induced by Ni$^{2+}$ appears in the photon energy range of 1.6–2.4 eV.
These energy ranges are in good agreement with that in which the Ni$^{2+}$ contribution to Faraday rotation occurs. Thus, the observed spectral change of Faraday rotation by the Ni substitution is most likely attributable to the crystal-field transition of octahedrally coordinated Ni$^{2+}$ ions.

A contribution to Faraday rotation made by other transitions lying at higher energy, such as the intraionic transition, however, cannot be ruled out. In order to conclusively determine the Ni$^{2+}$ contribution to Faraday rotation in the hexaferrite, further complementary data, such as a Faraday ellipticity spectrum, will need to be taken in the extended photon energy range.

IV. CONCLUSIONS

We have successfully grown Pr–Ni substituted Ba hexaferrite films on GGG substrates by rf sputtering and examined the contribution of the Pr$^{3+}$ and Ni$^{2+}$ ions to the MO properties. The films grew with the $c$ axis preferentially oriented normal to the film surface. The SEM and TEM observations revealed that the crystal-grain size in the films increased from several nm to about 300 nm with increasing rf power density. The films with larger grains showed higher $M_s$ and lower $H_c$. The Ni substitution induced a large negative Faraday rotation in the photon energy range of 2.1–2.6 eV, while no contribution of the Pr$^{3+}$ ion to Faraday rotation was observed. The induced spectral change is most likely ascribable to the crystal-field transitions of octahedrally coordinated Ni$^{2+}$ ions in the 2 eV range.